

Product Features

- Most precise single, OCXO in the industry
- Stability to ±2 ppb (commercial temperature) and ±3 ppb (industrial temperature)
- Excellent phase noise performance (-155 dBc at 10kHz offset)
- · Custom capabilities for specific application optimization
- RoHS 5/6 now RoHS 6/6 in development





Product Description

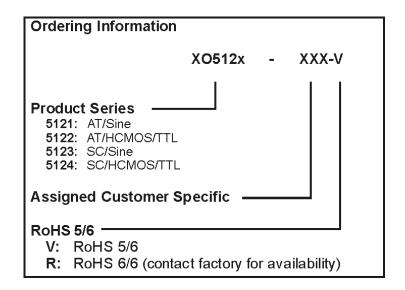
The XO5120 series is an industry standard 1" x 1.4" single OCXO which offers the best in phase noise combined with stability over a wide range of operating temperatures. With output logic (HC-MOS/TTL) or sinewave, this product fits most applications. The XO5120 series is based on a standard design platform that can then be tailored to the customer's specific requirements with little extra effort. Standard frequencies of 10.00, 12.80, 13.00, 16.384, and 20.00MHz are available as standard designs. Other frequencies between 10 and 100MHz can be developed in a short time.

Product Applications

The basis for all reference timing sources. With stability to +/-2ppb, this device even replaces Double OCXOs (DOCXO) in some applications. It can be used in:

- Microwave radios
- Base stations
- Test and Measurement equipment
- Reference timing circuits

Product Ordering Information





Performance Characteristics

Optional Temperature Ranges and Frequency Stabilities (F/T)			
OTR °C	SC-Cut	AT-Cut	
0 to +50	±2x10 ⁻⁹	±2x10 ⁻⁸	
0 to +70	±2x10 ⁻⁹	±2x10 ⁻⁸	
-10 to +70	±3x10 ⁻⁹	±2x10 ⁻⁸	
-30 to +70	±3x10 ⁻⁹	±3x10 ⁻⁸	
-40 to +70	±3x10 ⁻⁹	±3x10 ⁻⁸	
-40 to +85	±3x10 ⁻⁹	±4x10 ⁻⁸	

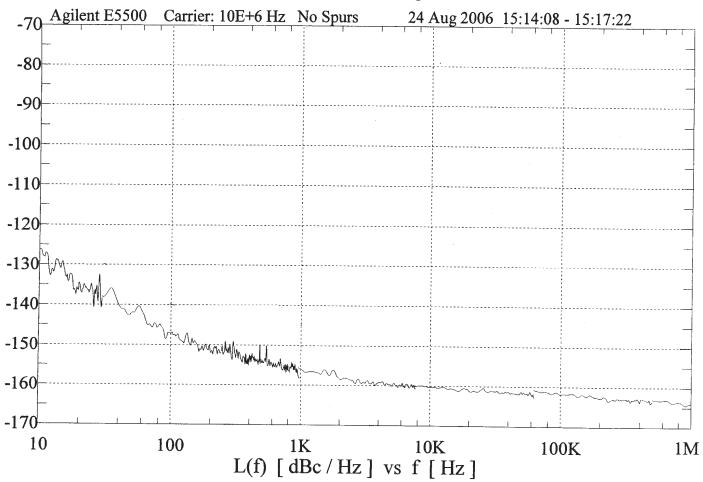
Frequency Range	1			
Operating Temperature				
Stability Over Temperature				
Short Term Stability				
Short Term Stability				
Daily Aging				
Daily Aging				
Yearly Aging				
Yearly Aging				
Yearly Aging				
Frequency vs. Supply				
Frequency vs. Load ±1				
Supply Voltage V _S 3.3 to 12 Volts Consult Factory				
Power Consumption				
Steady Sate @ 25°C To within ±1 x 10 ⁻⁷ in 3 minutes Minutes				
Steady Sate @ 25°C To within ±1 x 10 ⁷ in 3 minutes Minutes				
Sinewave Output Signal Level Output Load H3 Dutput Load Sinewave Output Load H3 Dutput Load Dutput Load Sinewave Output Load Sinewave Output Load Sinewave Output Load H3 Sinewave Output Load Sinewave				
Sinewave Output Signal Level Output Load H3 Dutput Load Sinewave Output Load H3 Dutput Load Dutput Load Sinewave Output Load Sinewave Output Load Sinewave Output Load H3 Sinewave Output Load Sinewave				
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Sinewave Output Signal Level Output Load H3 Dutput Load Sinewave Output Load H3 Dutput Load Dutput Load Sinewave Output Load Sinewave Output Load Sinewave Output Load H3 Sinewave Output Load Sinewave				
Output Load 50 Ω Frequency Adjustment (Pin 7) Slope Positive Consult Factory External Voltage Range Range Input Impedance (Pin 7) ±4 ppm ppm pm p				
Frequency Adjustment (Pin 7) Slope External Voltage V _C 0 10 Volts Consult Factory AT-Cut ppm AT-Cut SC-Cut Frequency Adjustment (Pin 7) 20				
Slope External Voltage Range				
External Voltage V _C 0 ±4 ±4 ppm AT-Cut SC-Cut				
Range 20 ±4 ppm ppm SC-Cut				
Range ±4 ppm SC-Cut				
Input Impedance (Pin 7) 20 KΩ				
Phase Noise AT-Cut SC-Cut Typical @ 10MHz 1 Hz				
Typical @ 10MHz 1 Hz -80 -90 dBc/Hz 10 Hz -115 -120 dBc/Hz 100 Hz -140 -140 dBc/Hz				
1 Hz -80 -90 dBc/Hz 10 Hz -115 -120 dBc/Hz 100 Hz -140 -140 dBc/Hz	AT-Cut SC-Cut			
10 Hz -115 -120 dBc/Hz 100 Hz -140 dBc/Hz				
100 Hz -140 -140 dBc/Hz				
1 kHz -145 -150 dBc/Hz				
10 kHz -150 -155 dBc/Hz				
Mechanical Shock Per MIL-STD-202, Method 213, Condition C				
	Per MIL-STD-202, Method 201 & 204			
Storage Temperature -55°C to 125°C	-55°C to 125°C			
Hermeticity Per MIL-STD-202, Method 112	Per MIL-STD-202, Method 112			
Max. Wave Soldering Cond.				

 $\label{local-local} \mbox{HCMOS Load - see load circuit diagram \#2. Sinewave Load - see load circuit diagram \#8}$

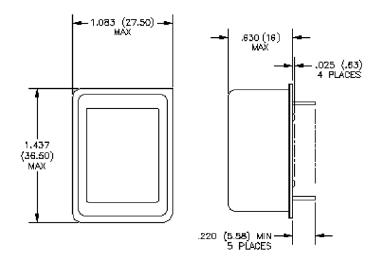


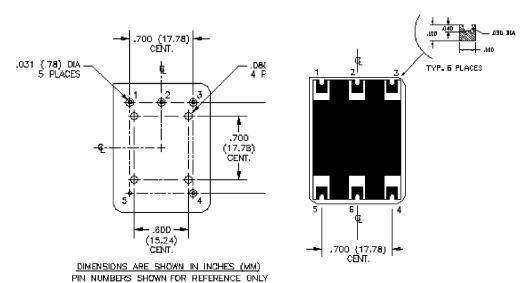
Phase Noise Plot

XO5123-007 S/N 50487 vs. Agilent 10811 Beater



Product Dimension & Pinout Information





Pin	Function	
1	Vtune	
2	Vref	
3	Supply	
4	RF Out	
5	Ground	
6*	OvenReady (Option) or N/C	

* Pin #6 may be enabled as "Oven Ready", No Connection, or removed entirely.



Devices

Handling Information

Although protection circuitry has been designed into the XO5120 oscillator, proper precautions should be taken to avoid exposure to electrostatic discharge (ESD) during handling and mounting. MtronPTI utilizes a human-body model (HBM) and a charged-device model (CDM) for ESD-susceptibility testing and protection design evaluation. ESD voltage thresholds are dependent on the circuit parameters used to define the mode. Although no industry-wide standard has been adopted for the CDM, a standard HBM (resistance = 1500 Ω , capacitance = 100 pF) is widely used and therefore can be used for comparison purposes. The HBM ESD threshold presented here was obtained using these circuit parameters.

Model	ESD Threshold, Minimum	Unit
Human Body	1500*	V
Charged Device	1500*	V

^{*} MIL-STD-833D, Method 3015, Class 1

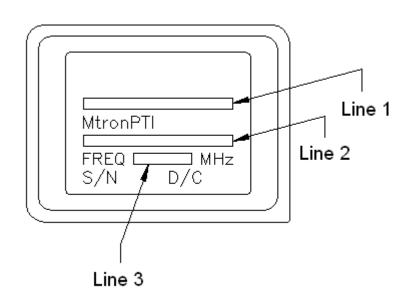
Quality Parameters

Environmental Specifications/Qualification Testing Performed on the XO5120 OCXO					
Test	Test Method	Test Condition			
Electrical Characteristics	Internal Specification	Per Specification			
Frequency vs. Temperature	Internal Specification	Per Specification			
Mechanical Shock	MIL-STD-202, Method 213, C	100 g, 6 ms			
Vibration	MIL-STD-202, Method 201-204	10 g from 10-2000 Hz			
Thermal Cycle	MIL-STD-883, Method 1010, B	-55 Deg. C to +125 Deg. C, 15 minute Dwell, 10 cycles			
Aging	Internal Specification	168 Hours at 105 Degrees C			
Gross Leak	MIL-STD-202, Method 112	30 Second Immersion			
Fine Leak	MIL-STD-202, Method 112	Must meet 1x10 ⁻⁸			
Solderability	MIL-STD-883, Method 2003	8 Hour Steam Age – Must Exhibit 95% coverage			
Resistance to Solvents	MIL-STD-883, Method 2015	Three 1 minute soaks			
Terminal Pull	MIL-STD-883, Method 2004, A	2 Pounds			
Lead Bend	MIL-STD-883, Method 2004, B1	1 Bending Cycle			
Physical Dimensions	MIL-STD-883, Method 2016	Per Specification			
Internal Visual	Internal Specification	Per Internal Specification			

Part Marking Guide

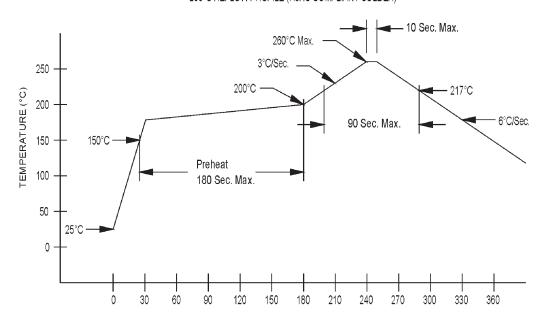
Line 1: Optional Customer Specified Line 2: MtronPTI Model Number

Line 3: Frequency (XXX.YYY)



Maximum Soldering Conditions

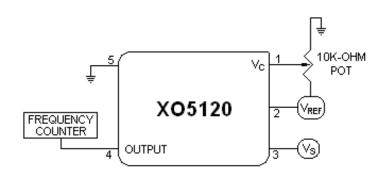
+260°C REFLOW PROFILE (RoHS COMPLIANT SOLDER)



Solder Conditions

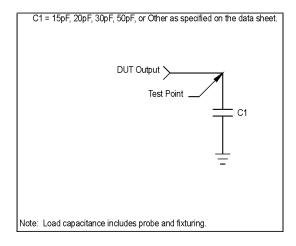
Note: Exceeding these limits may damage the device.

Typical Test Circuit

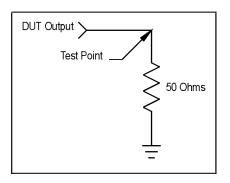


Load Circuit

Load Circuit #2 - HCMOS



Load Circuit #8 - Sinewave - 50 Ohms



Product Revision Table

Date	Revision	PCN Number	Details of Revision

For custom products or additional specifications contact our sales team at 800.762.8800 (toll free) or 605.665.9321

For more information on this product visit the MtronPTI website at www.mtronpti.com